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<b>INFORMATION DISCLOSURE STATEMENT TRANSMITTAL</b>  To Commissioner For Patents Enclosed herewith is a Form PTO-1449, any required copies of documents listed thereon, and any concise explanation of their relevance is indicated below per 37 CFR 1.97.	<b>Application Number</b>	
	<b>Filing Date</b>	
	<b>First Named Inventor</b>	SHANNON, JOHN M.
	<b>Group Art Unit</b>	
	<b>Examiner Name</b>	
	<b>Atty. Docket Number</b>	GB04 0023 US1

U.S. PATENT DOCUMENTS					
Examiner Initials*	Cite No. <sup>1</sup>	Document Number No.-Kind Code <sup>2</sup> (if known)	Publication Date MM-DD-YYYY	Name of Patentee or Applicant of Cited Document	Pages, Columns Lines, Where Relevant Passages or Relevant Figures Appear
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FOREIGN PATENT DOCUMENTS						
Examiner Initials*	Cite No. <sup>1</sup>	Document Number (ctry <sup>3</sup> -no.- <sup>4</sup> kind <sup>2</sup> , if known)	Publication Date MM-DD-YYYY	Name of Patentee or Applicant of cited document	Pages, Columns Lines, Where Relevant Passages or Relevant Figures Appear	T <sup>6</sup>

NON-PATENT LITERATURE DOCUMENTS			
Examiner Initials*	Cite No. <sup>1</sup>	Include name of the author (in capital letters), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published.	T <sup>4</sup>
	1	GADELRAH S. M. : "THE SOURCE-GATED AMORPHOUS SILICON PHOTO-TRANSISTOR"; IEEE ELECTRON DEVICES VOL. 44 NO. 10; OCT. 1997. PP 1789-1794.	
	2	SHANNON J. M. ET AL. : "SOURCE-GATED THIN-FILM TRANSISTORS"; IEEE ELECTRON DEVICE LETTERS VOL. 24 NO. 6; JUNE 2003. PP 405-407.	

<b>Examiner Signature</b>	/Que Tan Le/	<b>Date Considered</b>	01/07/2010
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<sup>1</sup> Unique citation designation number. <sup>2</sup> See attached Kinds of U.S. Patent Documents. <sup>3</sup> Enter Office that issued the document, by the two-letter code (WIPO Standard ST.3). <sup>4</sup> For Japanese patent documents, the indication of the year of the reign of the Emperor must precede the serial number of the patent document. <sup>5</sup> Kind of document by the appropriate symbols as indicated on the document under WIPO Standard ST. 16 if possible. <sup>6</sup> Applicant is to place a check mark here if English language Translation is attached.

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